BT236X series F and G

6 A Four-quadrant triacs Rev. 3 — 3 November 2011

Product data sheet

1. **Product profile**

1.1 General description

Passivated triacs in a full pack, plastic package intended for use in applications requiring high bidirectional transient and blocking voltage capability and thermal cycling performance.

1.2 Features and benefits

Isolated package

High I_{TSM}

1.3 Applications

- Lamp dimmers
- Motor speed controllers
- High inrush resistive loads
- Heating and static switching

1.4 Quick reference data

- V_{DRM} ≤ 600 V (BT236X-600_600F_600G)
- $V_{DRM} \le 800 \text{ V (BT236X-800_800G)}$
- $I_{TSM} \le 65 \text{ A (t = 20 ms)}$
- $I_{T(RMS)} \le 6 A$

- I_{GT} ≤ 35 mA (BT236X-600_800)
- $I_{GT} \le 25 \text{ mA (BT236X-600F)}$
- $I_{GT} \le 50 \text{ mA (BT236X-600G_800G)}$

Pinning information

Table 1. **Pinning**

	•		
Pin	Description	Simplified outline	Symbol
1	main terminal 1 (T1)		. .
2	main terminal 2 (T2)	mb	T2—T1
3	gate (G)		`G sym051
mb	mounting base; isolated		
		SOT186A (3-lead TO-220	F)



3. Ordering information

Table 2. Ordering information

Type number	Package								
	Name	Description	Version						
BT236X-600	3-lead	plastic single-ended package; isolated heatsink mounted; 1 mounting hole;	SOT186A						
BT236X-600F	TO-220F	3 lead TO-220 'full pack'							
BT236X-600G									
BT236X-800									
BT236X-800G									

4. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage				
	BT236X-600		<u>[1]</u> _	600	V
	BT236X-600F		<u>[1]</u> _	600	V
	BT236X-600G		<u>[1]</u> _	600	V
	BT236X-800		-	800	V
	BT236X-800G		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_h \le 88 ^{\circ}\text{C}$; see Figure 4 and 5	-	6	Α
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_j = 25$ °C prior to surge; see Figure 2 and 3			
		t = 20 ms	-	65	А
		t = 16.7 ms	-	71	А
l ² t	I ² t for fusing	t = 10 ms	-	21	A^2s
dI _T /dt	rate of rise of on-state current	$I_{TM} = 12 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$			
		T2+ G+	-	50	A/μs
		T2+ G-	-	50	A/μs
		T2- G-	-	50	A/μs
		T2- G+	-	10	A/μs
I_{GM}	peak gate current		-	2	Α
V_{GM}	peak gate voltage		-	5	V
P_GM	peak gate power		-	5	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	+150	°C
Tj	junction temperature		-	125	°C

^[1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6 A/μs.

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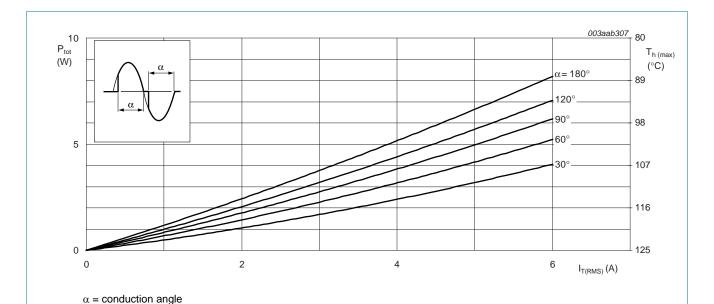


Fig 1. Total power dissipation as a function of RMS on-state current; maximum values

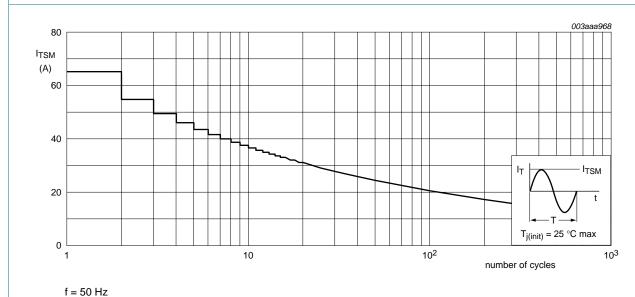
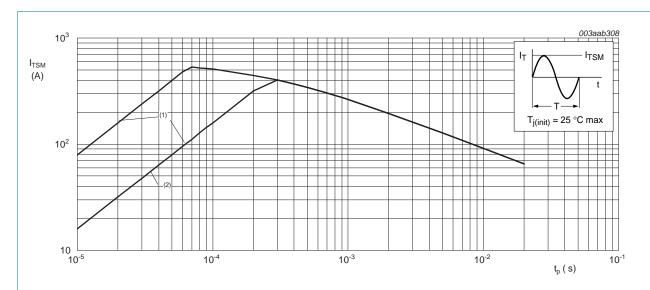


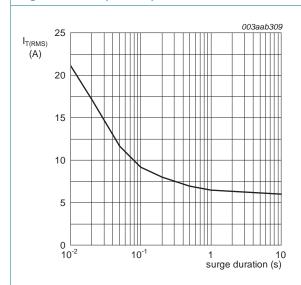
Fig 2. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values



 $t_p \le 20 \text{ ms}$

- (1) dI_T/dt limit
- (2) T2- G+ quadrant

Fig 3. Non-repetitive peak on-state current as a function of pulse duration; maximum values



 $f = 50 \text{ Hz}; T_h \leq 88 \text{ }^{\circ}\text{C}$

Fig 4. RMS on-state current as a function of surge duration; maximum values

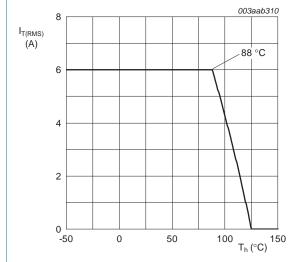


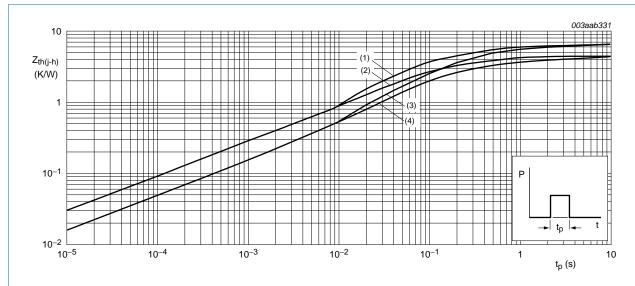
Fig 5. RMS on-state current as a function of heatsink temperature; maximum values

5. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
41() 11)	thermal resistance from junction to heatsink	see Figure 6	<u>[1]</u> -	-	4.5	K/W
		see Figure 6	[2] _	-	6.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	-	55	-	K/W

- [1] Full or half cycle with heatsink compound
- [2] Full or half cycle without heatsink compound



- (1) Unidirectional without heatsink compound
- (2) Unidirectional with heatsink compound
- (3) Bidirectional without heatsink compound
- (4) Bidirectional with heatsink compound

Fig 6. Transient thermal impedance from junction to heatsink as a function of pulse duration

6. Isolation characteristics

Table 5. Isolation limiting values and characteristics

 $T_h = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{isol(rms)}$	RMS isolation voltage	from all three terminals to external heatsink; f = 50 Hz to 60 Hz; sinusoidal waveform; RH ≤ 65 %; clean and dust free	-	-	2500	V
C _{isol}	isolation capacitance	from pin 2 to external heatsink; f = 1 MHz	-	10	-	pF

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7. Static characteristics

Table 6. Static characteristics

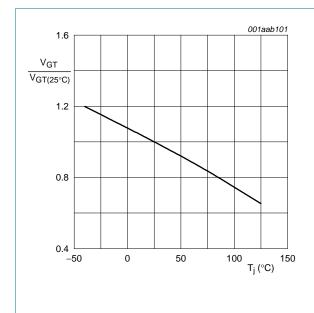
 $T_i = 25$ °C unless otherwise specified.

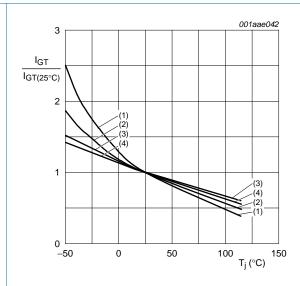
Symbol	Parameter	Conditions		236X-6 236X-8		BT	236X-60	00F		236X-60 236X-80		Unit
			Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
I _{GT}	gate trigger current	$V_D = 12 V;$ $I_T = 0.1 A;$ see <u>Figure 8</u>										
		T2+ G+	-	5	35	-	5	25	-	5	50	mΑ
		T2+ G-	-	8	35	-	8	25	-	8	50	mΑ
		T2- G-	-	11	35	-	11	25	-	11	50	mA
		T2- G+	-	30	70	-	30	70	-	30	100	mΑ
IL	latching current	$V_D = 12 \text{ V};$ $I_{GT} = 0.1 \text{ A};$ see <u>Figure 10</u>										
		T2+ G+	-	7	30	-	7	30	-	7	45	mΑ
		T2+ G-	-	16	45	-	16	45	-	16	60	mΑ
		T2- G-	-	5	30	-	5	30	-	5	45	mΑ
		T2- G+	-	7	45		7	45	-	7	60	mΑ
I _H	holding current	$V_D = 12 V;$ $I_{GT} = 0.1 A;$ see <u>Figure 11</u>	-	5	20	-	5	20	-	5	40	mA
V _T	on-state voltage	I _T = 10 A; see <u>Figure 9</u>	-	1.3	1.65	-	1.3	1.65	-	1.3	1.65	V
V _{GT}	gate trigger voltage	$V_D = 12 V;$ $I_T = 0.1 A;$ see <u>Figure 7</u>	-	0.7	1.5	-	0.7	1.5	-	0.7	1.5	V
		$V_D = 400 \text{ V};$ $I_T = 0.1 \text{ A};$ $T_j = 125 \text{ °C}$	0.25	0.4	-	0.25	0.4	-	0.25	0.4	-	V
I _D	off-state current	$V_D = V_{DRM(max)};$ $T_j = 125 {}^{\circ}C$	-	0.1	0.5	-	0.1	0.5	-	0.1	0.5	mA

8. Dynamic characteristics

Table 7. Dynamic characteristics

Symbol Parameter	Parameter	Conditions	BT236X-600 BT236X-800		BT236X-600F			BT236X-600G BT236X-800G			Unit	
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max		
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 0.67 V_{DRM(max)};$ $T_j = 125 ^{\circ}C;$ exponential waveform; gate open circuit	100	250	-	50	250	-	200	250	-	V/μs
dV _{com} /dt	rate of change of commutating voltage	$V_{DM} = 400 \text{ V};$ $T_j = 95 ^{\circ}\text{C};$ $I_{T(RMS)} = 6 \text{ A};$ $dI_{com}/dt = 3.6 \text{ A/ms};$ gate open circuit; see Figure 12	-	20	-	-	20	-	10	20	-	V/μs
t _{gt}	gate- controlled turn-on time	$I_{TM} = 12 \text{ A};$ $V_D = V_{DRM(max)};$ $I_G = 0.1 \text{ A};$ $dI_G/dt = 5 \text{ A}/\mu s$	-	2	-	-	2	-	-	2	-	μS

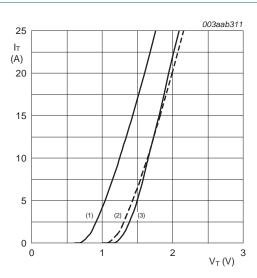




- (1) T2-G-
- (2) T2+G-
- (3) T2+ G+
- (4) T2-G+

Fig 7. Normalized gate trigger voltage as a function of junction temperature

Fig 8. Normalized gate trigger current as a function of junction temperature



 $V_0 = 1.26 \text{ V}$

 $R_s = 0.0378 \Omega$

(1) $T_i = 125 \,^{\circ}C$; typical values

(2) T_i = 125 °C; maximum values

(3) $T_j = 25$ °C; maximum values

Fig 9. On-state current as a function of on-state voltage

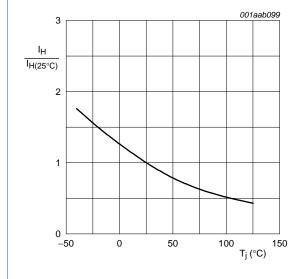


Fig 11. Normalized holding current as a function of junction temperature

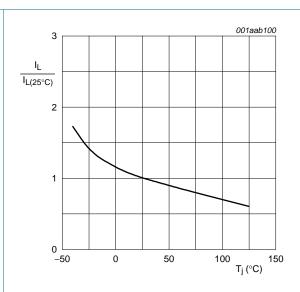
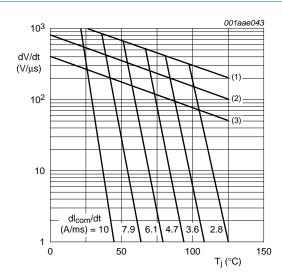


Fig 10. Normalized latching current as a function of junction temperature



The triac should commutate when the dV/dt is below the value on the appropriate curve for pre-commutation dl_T/dt .

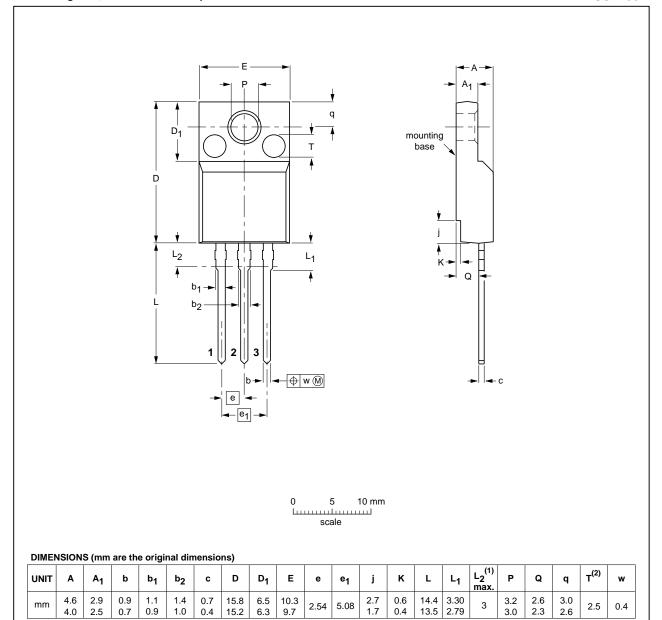
- (1) Off-state dV/dt limit for BT236X-600G_800G
- (2) Off-state dV/dt limit for BT236X-600_800
- (3) Off-state dV/dt limit for BT236X-600F

Fig 12. Typical commutation dV/dt as a function of junction temperature

9. Package outline

Plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 'full pack'

SOT186A



Notes

- 1. Terminal dimensions within this zone are uncontrolled.
- 2. Both recesses are \varnothing 2.5 \times 0.8 max. depth

OUTLINE VERSION		REFER	ENCES	EUROPEAN	ISSUE DATE
	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT186A		3-lead TO-220F			02-04-09 06-02-14

Fig 13. Package outline SOT186A (3-lead TO-220F)

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10. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
BT236X_SER_F_G v.3	20111103	Product data sheet	-	BT236X_SER_F_G v.2				
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 							
 Legal texts have been adapted to the new company name where appropriate. 								
BT236X_SER_F_G v.2	20060314	Product data sheet	-	BT236X_SER_F_G v.1				
BT236X_SER_F_G v.1	20060209	Product data sheet	-	-				

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions"
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